

Power Supply IC Series for TFT-LCD Panels

5V Input Multi-channel System Power Supply IC



BD9862MUV No.10035EAT16

Description

The BD9862MUV is a 3ch system power supply for mobile TFT liquid crystal panels. Operable at VBAT=1.8V, CH2 & CH3 adopts the original PWM/PFM automatic switching control charge pump and realizes high efficiency in full-load range.

Features

- 1) Input voltage range: 1.8V~4.5V (The input voltage can be 5.5V if a double charge pump is not used)
- 2) The step-up switching regulator has a built-in output FET (CH1)
- 3) There is a built-in PWM/PFM automatic switching charge pump circuit with a fixed PWM terminal (CH2,3)
- 4) Switching regulator oscillation frequency: MHz(typ.)
- 5) Charge pump oscillation frequency: 500kHz(typ.)
- 6) There is a built-in circuit to discontinue output (timer latch type) in the event of overload
- 7) Package VQFN024V4040

Applications

Small & medium TFT liquid crystal displays etc.

● Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Ratings	Unit	
Maximum adding power supply voltage	VBAT	-0.3 ~ 7	V	
	LX	-0.3 ~ 18	V	
Maximum adding voltage	FB1, INV1, INV2, UVLOSET, C2N, VIN2A, CN, CP, CPOUT, REGOUT, PWM, RT ,VREF ,NON3	-0.3~7		
	VIN3, C3P, Vo2, C2P, VIN2B	-0.3~15.5		
Power dissipation	Pd	0.34(*1)	W	
Power dissipation	Fu	0.70(*2)		
Operating temperature range	Topr	-40 ~ +85	°C	
Storage Temperature Range	Tstg	-55 ~ +150	°C	
Junction temperature	Tjmax	+150	°C	

^(*1) When used as a stand-alone IC (for Ta=25°C and over), the value is reduced by 27mW/°C.

●Operating Conditions(Ta=25°C)

Parameter	Symbol	Ratings			1.1-24	
		MIN	TYP	MAX	Unit	condition
Power Supply Voltage	VBAT	1.8	-	4.5 ^(‰1)	V	
CH1Output Voltage	Vo1	-	-	15	V	
CH2 Output Voltage	Vo2	-	-	15	V	
CH3 Output Voltage	Vo3	-15	-	-	V	
Starting capacity, adding charge pump flying capacitor	Cflys,Cflya	0.1	0.22	-	μF	
Reversing capacity charge pump flying capacitor	Cflyi	0.022	0.047	-	μF	
Starting charge pump Output capacitance	CCPOUT	1.0	2.0	-	μF	CCPOUT≧Cfly*10
Switching regulator oscillation frequency	fOSC1	700	1.0	1.4	MHz	RRT=82kΩ~180kΩ
Charge pump oscillation frequency	fOSC2	350	500	700	kHz	RRT=82kΩ~180kΩ
CH1 PowerNMOS Drain current	lidn1	-	-	1.0	Α	

^(%1) When using a double charge pump for starting. 5.5V when not using a double charge pump

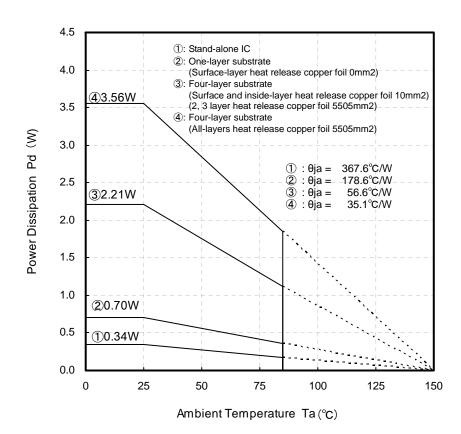
^(*2) When used for Printed Circuit Boards (glass epoxy board of 74.2mmx74.2mmx1.6mm) mounting for Ta=25°C and over, the value is reduced by 5.6mW/°C.

● Electrical Characteristics (unless otherwise specified,Ta=25°C,VBAT=2.5V)

Parameter		0 1 1		Limits			
		Symbol	MIN	TYP	MAX	Unit	Condition
[Starting circuit part]							
Output voltage		Vcpout	3.7	4.2	4.7	V	Iout=0~10mA
VBAT Voltage to start operation		Vst	-	-	1.8	V	
[Soft start part]							
CH1Soft start time		Tss1	0.5	1.0	2.0	ms	R_{RT} =120 $k\Omega$
CH2 Soft start time		Tss2	3.5	5.0	6.5	ms	R_{RT} =120 $k\Omega$
CH3 Soft start time		Tss3	3.5	5.0	6.5	ms	R_{RT} =120k Ω
[Oscillation circuit]							
Switching regulator from	equency	fosc1	0.9	1.0	1.1	MHz	R _{RT} =120kΩ
Charge Pump Freque	ncy	fosc2	450	500	550	kHz	R _{RT} =120kΩ
[Regulator]				1			
Output Voltage		VREGOUT	3.4	3.5	3.6	V	Iout=0~10mA,VBAT=2.0V~4.5V
【PWM Comparator】						•	•
MAX Duty1		Dmax1	85	90	95	%	
MAX Duty2		Dmax2	40	45	50	%	
MAX Duty3		Dmax3	40	45	50	%	
[Error amplifier]		1		1	1		,
INV1Threshold Voltage	je	VINV1	0.985	1.0	1.015	V	
INV2Threshold Voltag	je	VINV2	0.985	1.0	1.015	V	
NON3Threshold Voltage		VNON3	0.985	1.0	1.015	V	Making VREF as absolute value
CH3 Error amplifier of	f set voltage	Voffset	-50	0	50	mV	
[Output part(Switchin	g Regulator]			1			
NMOSFET ON Resist	tance	RonN1	0.2	0.45	0.7	Ω	REGOUT=3.5V
Leak current when NN	MOSFET OFF	IreakN1	-	-	10	μA	UVLOSET=0V
[Adding step-up char	ge pump]			1			
Output impedance		R2	-	53	90	Ω	Io=0~10mA,VIN2A=3.5V, VIN2B=10V,INV2=GND
[Inverted charge pur	np]						
Output FET	PMOS	RonP3	-	20	40	Ω	VIN3=10V
ON resistance	NMOS	RonN3	-	10	20	12	VIIN3=10V
[Control Terminal Pa	rt】						
PWM Terminal pull down resistance		RPWM	0.5	1	2	ΜΩ	
PWM Terminal	Operation	VPWMH	1.2	-	VBAT	V	PWM Fixed mode
control voltage	Non-operation	VPWML	0	-	0.3	V	PWM/PFM Auto shift mode
[Short circuit protecti	on circuit]						
Timer Latch Time		Latch	110	131	150	ms	R _{RT} =120kΩ
[UVLO]							
Relief voltage threshold		UVth	0.97	1.0	1.03	V	
Hysteresis		UVhy	50	75	100	mV	
[Circuit current]							
Circuit current during operation (VBAT terminal inflow current)		IVBAT	0.4	0.8	1.6	mA	VBAT=5V, UVLOSET=INV1=INV2=5V NON3=-0.2V

Olt is not the radiation-proof design for this product.

● Power Dissipation Reduction



●Reference Data(Unless specified Ta=25°C,VCC=2.5V,R_{RT}=120kΩ)

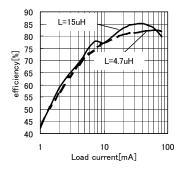


Fig.1 CH1Current Load to Efficiency (Vo1=10V)

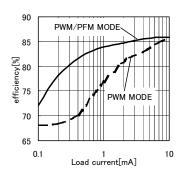


Fig.2 CH2 Current Load to Efficiency (VIN2A=3.5V,VIN2B=10V,Vo2=12V)

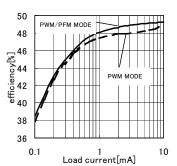


Fig.3 CH3 Current Load to Efficiency (VIN3=10V,Vo3=-5V)

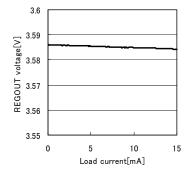


Fig.4 REGOUT
Output Load Regulation

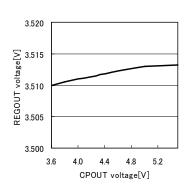


Fig.5 REGOUT Output Line Regulation

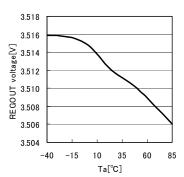


Fig.6 REGOUT Output Voltage Temperature Feature

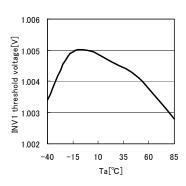


Fig.7 INV1 Threshold Voltage Temperature Feature

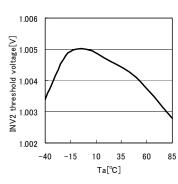


Fig.8 INV2 Threshold Voltage Temperature Feature

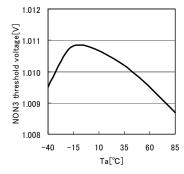


Fig.8 NON3 Threshold Voltage Temperature Feature

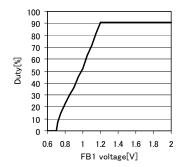


Fig.10 CH1 FB1Voltage-On Duty Feature

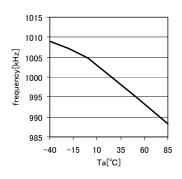


Fig.11 CH1 Switching Frequency Temperature Feature

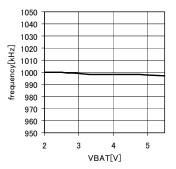


Fig.12 CH1 Switching Frequency to VBAT Voltage Feature

● Reference data(Unless specified Ta=25°C, VCC=2.5V)

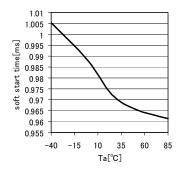


Fig.13 CH1 Soft Start Temperature Feature

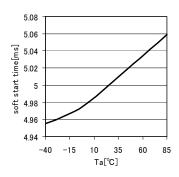


Fig.14 CH2,CH3 Soft Start Temperature Feature

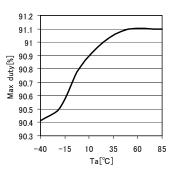


Fig.15 CH1
Max Duty Temperature Feature

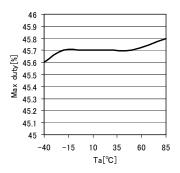


Fig.16 CH2,CH3 Max Duty Temperature Feature

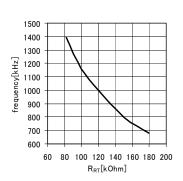


Fig.17 RT Resistance to CH1 Switching Frequency Feature

Block Diagram

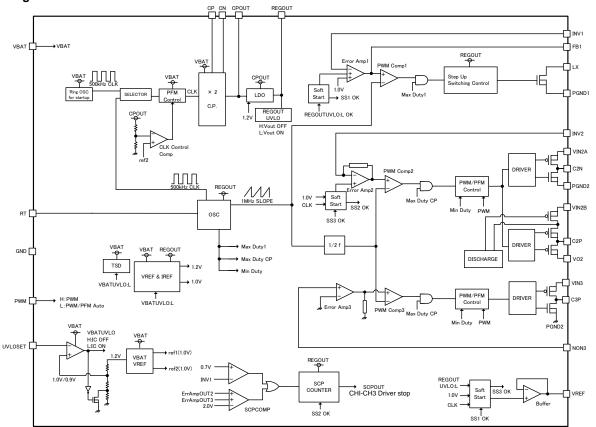


Fig.18

●Terminal Location Diagram

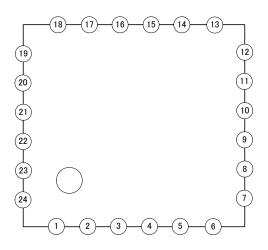


Fig.19

●Terminal Number and Terminal Name and Function

Terminal Number	Terminal Name	Function	
1	FB1	Error amplifier output terminal for CH1	
2	INV2	Error amplifier inverted input terminal for CH1	
3	UVLOSET	UVLO Standard voltage terminal	
4	VIN3	Reversing charge pump input terminal	
5	C3P	Reversing charge pump. Flying capacitor H-side input terminal	
6	PGND2	Built-in EFT grounding terminal for CH2,3	
7	C2N	Adding step-up charge pump. Flying capacitor L-side input terminal	
8	VIN2A	Adding step-up charge pump input terminal	
9	VO2	Adding step-up charge pump output terminal	
10	C2P	Adding step-up charge pump. Flying capacitor H-side input terminal	
11	VIN2B	Adding step-up charge pump input terminal	
12	LX	Inductor connecting terminal	
13	PGND1	Built-in FET grounding terminal for CHI1	
14	CN	Start-up charge pump. Flying capacitor L-side input terminal	
15	СР	Start-up charge pump .Flying capacitor H-side input terminal	
16	VBAT	Power supply input terminal	
17	CPOUT	Start-up charge pump output terminal	
18	REGOUT	Regulator output terminal	
19	PWM	Charge pump block PWM/PFM switching terminal	
20	GND	Grounding terminal	
21	RT	Connecting terminal of resistor for frequency timing setting	
22	VREF	Standard voltage output terminal	
23	NON3	Non-reversing input terminal of error amplifier for CH3	
24	INV1	Reversing input terminal of error amplifier for CH1	

BD9862MUV Technical Note

System Description

BD9862MUV is a 3ch system power supply optimized for TFT liquid crystal displays.

Features of each channel are explained as follows

OCH1

This is a voltage mode switching regulator with a built-in high voltage-resistant output FET. Capable of high-speed operation at the maximum switching frequency of 1.4MHz, and compatible with a high step-up ratio with Max Duty of 90%(typ.).

OCH₂

It's a PWM/PFM automatic switching control with a variable-voltage adding charge pump. Due to intermittent switching at the time of PFM mode, the switching loss is reduced, so high efficiency is realized even in light load conditions. Moreover, it is capable of operating at the maximum switching frequency of 700KHz because of a built-in high voltage resistant, high-speed FET driver. In addition, it is equipped with an On Duty prediction function, so the output voltage ripple is lowered considerably even at the time of PFM operation. Due to the built-in output discharge resistor ($1k\Omega$ typ.) and FET phase compensation circuit, it can operate with two capacitors and two resistors.

OCH3

It includes a PWM/PFM automatic switching control, variable-voltage reversing charge pump controller. The control method is the same as CH2.

Block functional descriptions

· Error amplifier block

Detects the output voltage with INV terminal (NON3 terminal in case of CH3), amplifies the error between it and standard voltage, and outputs from the FB terminal. The accuracy is ±1%(1.5% in case of CH2 & CH3).

PWM(Pulse Width Modulation)Convertor block

The PWM convertor inputs the error detected by the error amplifier and outputs the PWM signal by comparing with a saw-tooth wave.

PWM/PFM Control Block

Due to the input of the PWM terminal, this block switches the CH2 & CH3 between the fixed PWM mode and the automatic switching mode of PFM(Pulse Frequency Modulation)/PWM. At the time of PFM mode, the efficiency under a light load is raised by controlling and making the lowest On Duty of PWM signal to be 7%(typ.) and reducing the number of switching times.

LDO Block

This is a power supply to operate the internal circuit. In addition, it can be used as input of VIN2B. The output voltage is 3.5V(typ.), and the maximum load is 10mA. Moreover, due to a built-in UVLO, the release voltage is 2.5V(typ) and the protective voltage is 2.4V(typ).

Start-up Charge Pump Block

If REGOUT is ≦2.5V(typ.), then the ring oscillator, which operates at 500kHz or so, is started and the double charge pump is operated. The clock pulse is controlled in such a way that the output voltage of this charge pump becomes 4.2V(typ.). Moreover, if REGOUT becomes more than 2.5V(typ.) (i.e. REGOUT>2.5V(typ.)), then the clock is supplied from the main OSC that creates a saw tooth wave. If the input voltage is usually more than 4.5V, then it is possible to bypass the start-up circuit. (refer to the application example)

OSC Block

It generates a saw-tooth wave and inputs it into the PWM comparator. It is possible to change the oscillating frequency by means of the resistor RT. Due to RRT=120k Ω , the CH1 operates at 1MHz(typ.). The double charge pump, CH2 and CH3 operate at 1/2 of CH1 frequency.

VREF Block

Generate the constant voltage that is standard inside the IC.

UVLO Block

Performs the under voltage lockout by detecting the VBAT voltage with the UVLOSET terminal. The UVLO voltage can be set by an external resistor.

Soft Start Block

Due to sweep-starting of the standard voltage of the error amplifier at the time of start-up, the excess input current & output voltage is reduced. Moreover, only at the time of soft start, the CH2 is regarded as the resistance value of $150\Omega typ$ between VIN2B & C2P and the CH3 is regarded as the resistance value of $60\Omega typ$ between VIN3 & C3P therefore the input current is limited.

Short-circuit protection of timer latch (SCP) block

Monitors the INV1 terminal and the error amplifier outputs of CH2 & CH3, and turns off the drivers of CH1~CH3 if a short-circuit condition continues for more than a certain period of time. The timer latch time is counted by the CH1 internal switching pulse. The counting is started when a short-circuit condition begins, ant the drivers are turned off when 131,072 is reached.

Example) if RRT=120k Ω , then 131072×(1/1[MHz])=131.072ms

· Thermal shutdown (TSD) block

Detects abnormal heat generation of the IC, stops the switching operation of all Ch and prevents the IC from thermal overload. The detecting temperature is 175° C(typ), and the hysteresis is 10° C(typ).

●Timing Chart

1) When Starting

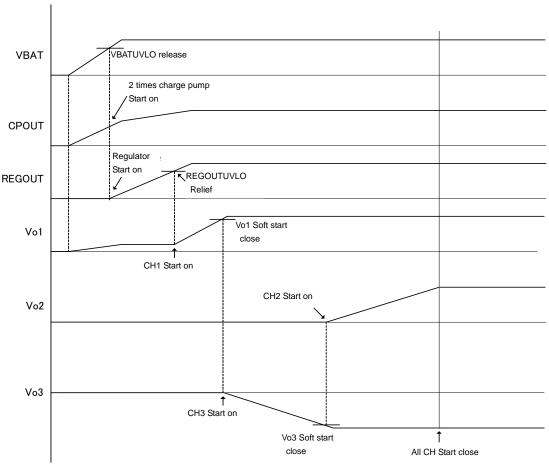


Fig.20

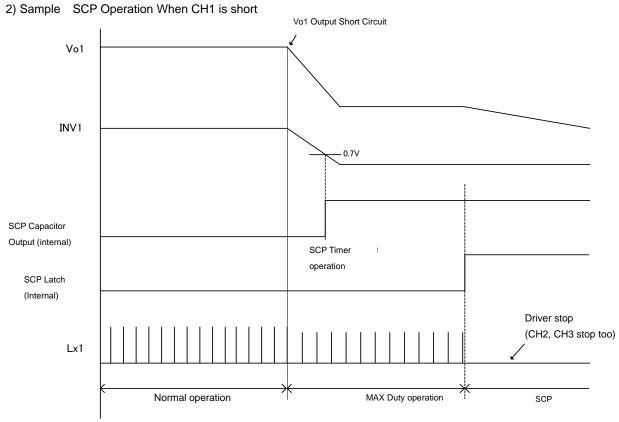
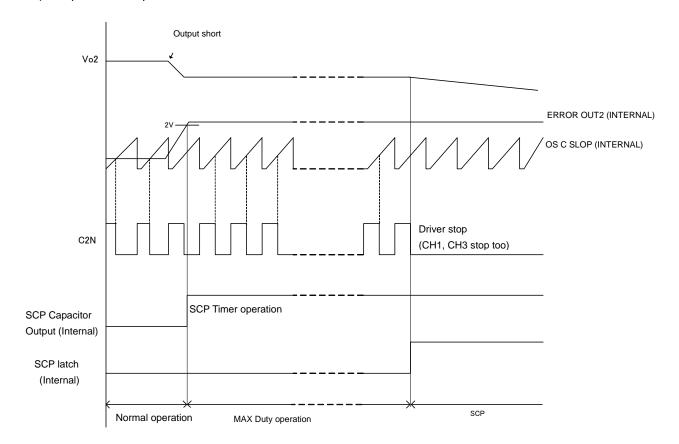


Fig.21

3) Sample② SCP Operation When CH2 is Short



*Operates similarly at the time of CH3 short-circuit.

Fig.22

Technical Note BD9862MUV

Method to select the application parts

1) Setting of output voltage

The output voltage VOUT is set by dividing the resistance of the external resistor.

CH1,CH2:VOUT=1+R2/R1

CH3:VOUT=-((R4/R3)+Voffset)

R1: Feedback resistor (GND side), R2: Feedback resistor (VOUT side), R3: Feedback resistor (VREF side),

R4: Feedback resistor (VOUT side)

2) Setting of the output inductor

The maximum current $I_{l,peak}$ that flows in the inductor is calculated by the sum of the average current $I_{l,peak}$ and the maximum value of ripple current ⊿l₁

$$I_{Lpeak} = \overline{I}_{L} + \Delta I_{L}$$

Generally ⊿I_L is set to about 30% of I_L.

The average current I_{\perp} and the ripple current ΔI_{\perp} are calculated according to the following formulas.

$$\overline{I_L}_{max} \ = \frac{V_{out}}{V_{in\,min}} I_{out\,\,max} \qquad \qquad \Delta I_L \ = \frac{V_{in\,min} \ \times \left(V_{out} \ - V_{in}\right)}{2 \times f_{osc} \ \times L \times V_{out}}$$

L: value of inductance fosc: switching frequency V_{inmax}: maximum input voltage V_{inmin}: minimum input voltage Vout: set value of output voltage

Please set in such a way that ILDeak (the rated value of inductor current) is not exceeded. If ILDeak exceeded, then the efficiency is lowered extremely and damage to the inductor is caused. Please set in such a way that a good margin is left because the inductance varies in value.

3) Setting of output capacitor

The capacitance & ESR of the output capacitor is influenced a great deal by output voltage ripple. Moreover, PFM mode intentionally makes the switching intermittent, so the output voltage ripple becomes larger compared with PWM mode. Please use an appropriate capacitor according to the service condition. In addition, please be sure to connect a ceramic capacitor of 1µF to REGOUT terminal.

It is assumed that this IC uses a multilayer ceramic capacitor. For small multilayer ceramic capacitors such as Size 1608 etc., its actual capacitance may be lower than its nominal one because of the voltage that is bypassed. Please check to confirm various characteristics such as DC bypass etc. before use.

4) Setting of flying capacitor

Please set the capacitance of the flying capacitor of the start-up charge pump not to exceed 1/10 of the capacitance of the CPOUT output capacitor. If it is more than 1/10 of the capacitance, damage may be caused.

5) Setting of the input capacitor

A bypass capacitor for input is necessary to the VBAT terminal. Due to input & output voltage, load and wiring pattern etc., the actual capacitance is different from the necessary one, so please carefully check to confirm.

6) Setting of CR for phase compensation

The CR for phase compensation is varied due to the characteristics of the capacitor & inductor,-which are used in the output part, the input & output voltage and the load current etc. The phase-compensation CR constant in a recommended circuit diagram is set according to the service conditions, but applications under other conditions than the various conditions mentioned will cause oscillation instability etc. Please contact our technical service department if any conditions are changed.

7) Setting of schottky diode in the output part

Please use a schottky diode with an allowable current more than I_{Lpeak} for the output part. Furthermore, it is necessary that the maximum reverse voltage is more than output voltage. Generally speaking, more lower the forward voltage, the higher the efficiency.

8) Setting of UVLO voltage

The VULO release voltage VUVLO can be set according to the following formula:

VUVLO=1+R2/R1(R1=GND-side resistance R2=VBAT-side resistance)

If you want to make the start-up of the IC to lag behind the rising edge of VBAT, connect a capacitor to the UVLOSET terminal and set the time constant.

9) Setting of oscillating frequency

Oscillating frequency can be adjusted by a resistor connected to the RT terminal.

The CH1 oscillating frequency fosc1 is determined by the formula shown below: fosc1=1/(8×10⁻¹²×R_{RT}+4×10⁻⁸)

The frequency calculated by the formula shown above is a theoretical value, so please refer to the above-mentioned reference data 「RT resistance vs. CH1 switching frequency characteristic」 for actual frequency.

BD9862MUV Technical Note

Operating Guidelines

PWM terminal

At Low the PFM mode skips the pulse of less than 7% On Duty. It is also switched over to the PWM mode if a certain amount of load is reached or exceeded while in PFM mode. Moreover, it is switched to PFM mode if the load becomes light. Please set the PWM terminal to High and use as the forced PWM mode if there is an influence of noise created by modulation of the switching frequency.

- SCP Function
 - In case of circuit stoppage due to SCP, the protection is released by setting the UVLOSET voltage to L and the VBATT to OFF.
- · CH2 adding charge pump

Please set the Vo2 so that the VIN2A+VIN2B become not more than 15V because the voltage that is the sum of the VIN2A voltage plus the VIN2B voltage is applied.

Technical Note

● Sample of Recommended Circuit

1) Sample of Input voltage 1.8V~4.5V application

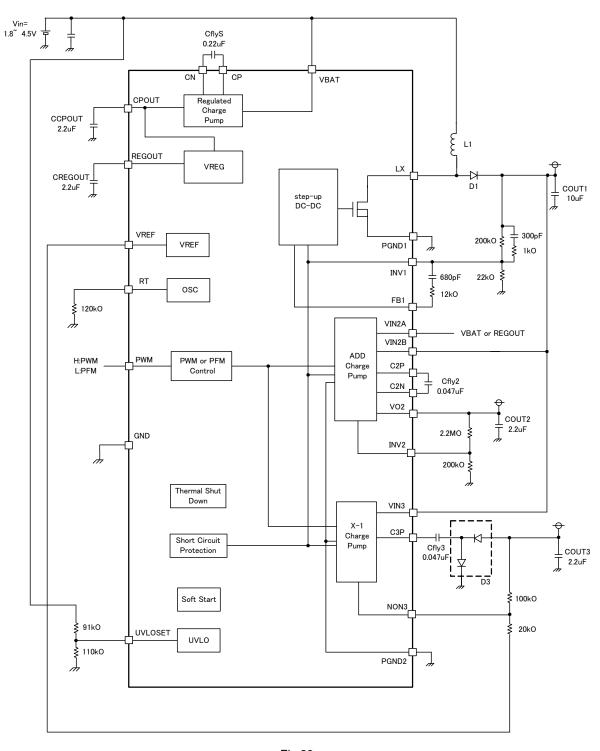


Fig.23

Recommended Parts

: NR4010T4R7M(TAIYO YUDEN) CCPOUT GRM188B30J225KE18(MURATA) L1 D1 : RB161VA-20(ROHM) **CREGOUT** : GRM155B30J105KE18 (MURATÁ) : DAN217U(ROHM) COUT2, COUT3: GRM188B31C225KE14D(MURATA) COUT1: GRM31CB31C106KA88(MURATA) : GRM155B10J224KE01(MURATA) Cflys : GRM219B30J106KE18(MURATA) : GRM155B11C473KA01(MURATA) Cfly2, Cfly3

2) Sample of Input voltage 4.5V~5.5V application

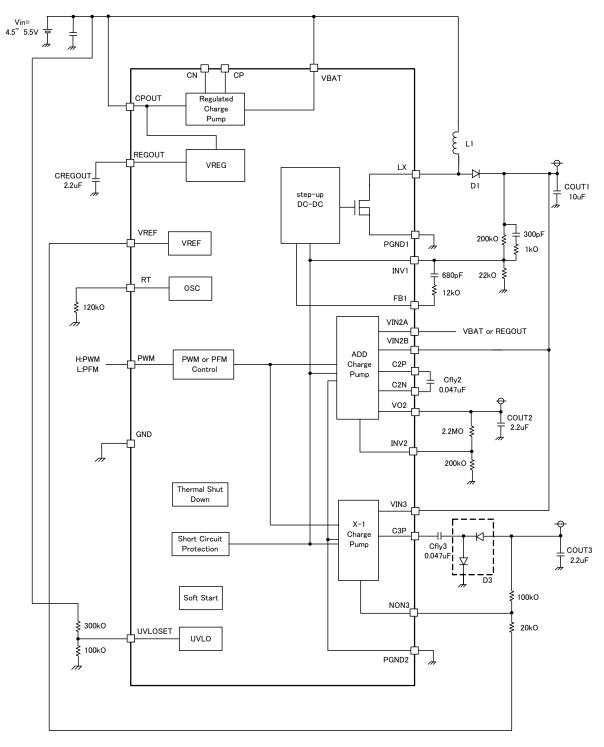


Fig.24

· Recommended Parts

Technical Note

●Input / Output Equivalent Circuit

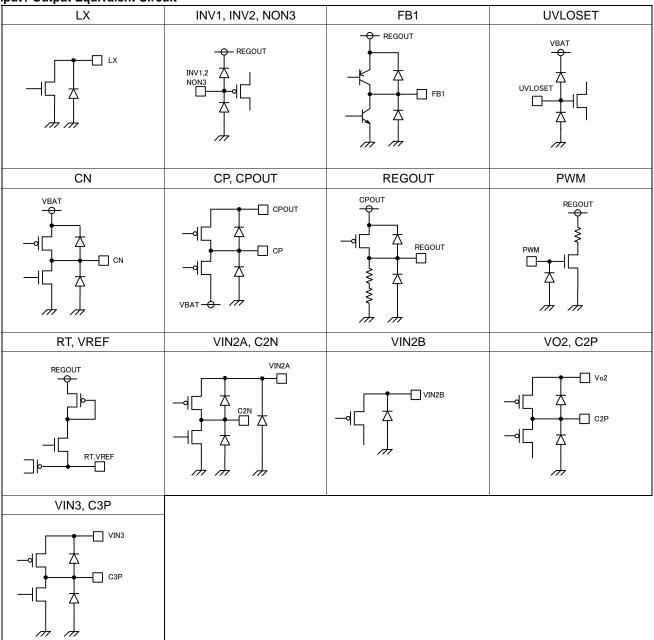


Fig.25 Input / Output Equivalent Circuit

●Points for attention on PCB layout

- ①Place the resistors and capacitors, that are connected to RT, INV1, FB1, INV2, NON3 and VREF, close to the terminals to avoid being affected by the wirings, where switching is large, such as LX1 wiring and flying capacitor wiring etc.
- 2) Place the inductor, schottky diode and flying capacitor close to the IC.
- ③Mount in such a way that the back side of the package serves as the GND potential which covers the largest space in the PCB. Heat dissipation performance is improved.

Notes for Use

1.) Absolute maximum ratings

This is a high quality product, but if absolute maximum rating such as applied voltage and operating temperature range is exceeded, then deterioration or breakdown may result. Moreover, such destructive conditions as short mode or open mode can not be assumed. If a particular mode such as exceeding the absolute maximum rating is assumed, consideration should be given to using physical safety measures such as a fuse.

CND Potential

The electric potential of the GND pin should be the lowest electric potential under any operating state. In addition, (including transient phenomenon), do not make the electrical potential of any pin lower than the GND's.

3.) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4.) Inter-pin shorts and mounting errors

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC.

In addition, shorts between output pins or between output pins and the power supply GND pin caused by the presence of a foreign object may result in damage to the IC.

5.) Operation in a strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

6.) Common impedance

Power supply and GND wiring should reflect consideration of the need to minimize ripples as much as possible., (which lower common impedance), by making wiring as short and thick as possible or incorporating inductance and capacitance.

7.) Thermal shutdown circuit (TSD circuit)

This IC incorporates a built-in thermal shutdown circuit (TSD circuit). The TSD circuit is designed not for the purpose of protection & guarantee of the IC, but only to shut the IC off to prevent thermal overload. Therefore, do not use the IC on the premise that this TSD circuit will be operated to shut the IC off (or the IC will be continued to be used after this TSD circuit is operated to shut the IC off).

8.) IC pin input

This monolithic IC contains the P+ isolation between adjacent elements in order to keep them isolated from the P substrate. Due to this P layer and the N layer of each element, the P/N junctions are formed and various kinds of elements are created.

For example, if a resistor and a transistor are connected with pins as shown in the Fig., then:

- othe P/N junction functions as a parasitic diode when
 - GND > (Pin A) for the resistor or GND > (Pin B) for the transistor (NPN).
- ○Moreover, when GND > (Pin B) for the transistor (NPN),

the parasitic NPN transistor is operated by N layer of other elements adjacent to the above-mentioned parasitic diode. The formation of parasitic elements as a result of the relationships of electric potentials is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with the circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as by the application of voltages lower than the GND (P substrate) voltage to input pins.

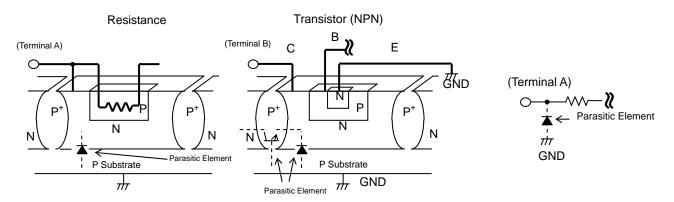
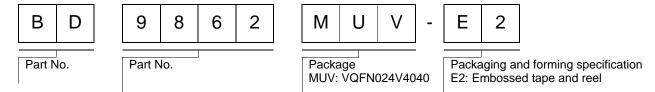
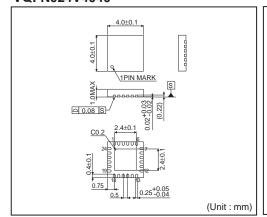


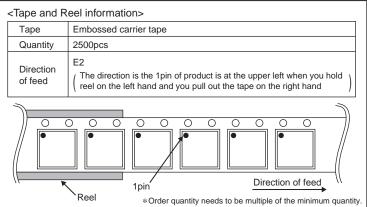
Fig.26 Simple Structure of monolithic IC (Sample)

Ordering Part Number



VQFN024V4040





Notice

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(Note1) Medical Equipment Classification of the Specific Applications

JÁPAN	USA	EU	CHINA
CLASSI	СГУССШ	CLASSIIb	СГУССШ
CLASSIV	CLASSII	CLASSIII	— CLASSⅢ

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Distribution Inventory

Part Number	BD9862MUV
Package	VQFN024V4040
Unit Quantity	2500
Minimum Package Quantity	2500
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes